

**Product data sheet** 

## 1. General description

Planar passivated SCR with sensitive gate in a SOT223 surface mountable plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

## 2. Features and benefits

- Sensitive gate
- Planar passivated for voltage ruggedness and reliability
- Direct triggering from low power drivers and logic ICs
- Surface mountable package

## 3. Applications

- Circuit breakers
- RCD/GFI/LCCB applications

### 4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DRM</sub>	repetitive peak off- state voltage		[1]	-	-	600	V
V <sub>RRM</sub>	repetitive peak reverse voltage			-	-	600	V
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4; Fig. 5</u>		-	-	8	A
I <sub>T(AV)</sub>	average on-state current	half sine wave; $T_{sp} \le 112 \text{ °C}$ ; Fig. 1		-	-	0.63	A
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	-	1	A
Static chara	cteristics						
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 25 °C; Fig. 9		20	50	200	μA

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state.





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## 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	4	а <del>-Ң</del> к
2	А	anode		G sym037
3	G	gate		
4	mb	mb; connected to anode	☐1	

## 6. Ordering information

Table 3. Ordering in	formation					
Type number	Package					
	Name	Description	Version			
BT168GW	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223			

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## 7. Limiting values

#### Table 4.Limiting values

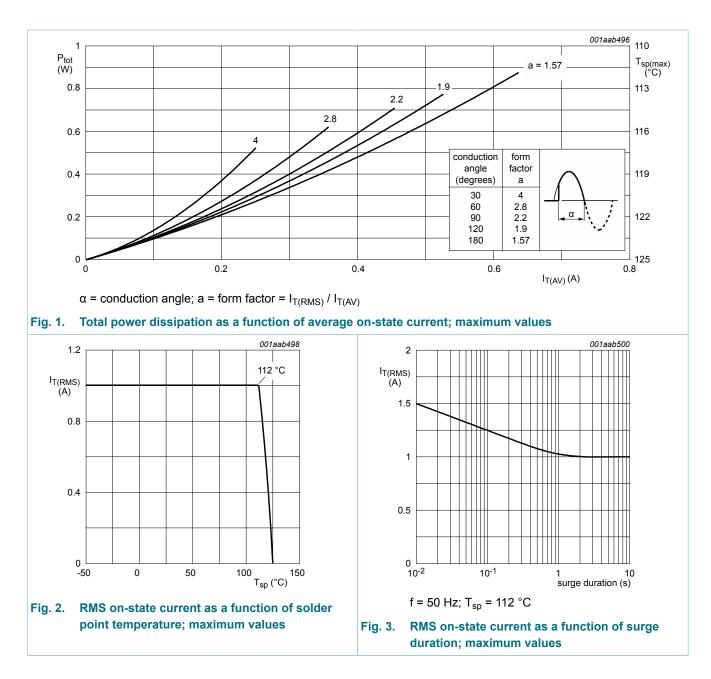
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		[1]	-	600	V
V <sub>RRM</sub>	repetitive peak reverse voltage			-	600	V
I <sub>T(AV)</sub>	average on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 1</u>		-	0.63	А
I <sub>T(RMS)</sub>	RMS on-state current	half sine wave; T <sub>sp</sub> ≤ 112 °C; <u>Fig. 2;</u> <u>Fig. 3</u>		-	1	A
I <sub>TSM</sub>	non-repetitive peak on-state current	half sine wave; T <sub>j(init)</sub> = 25 °C; t <sub>p</sub> = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>		-	8	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms		-	9	A
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; SIN		-	0.32	A <sup>2</sup> s
dI <sub>T</sub> /dt	rate of rise of on-state current	$I_T$ = 2 A; $I_G$ = 10 mA; $dI_G/dt$ = 100 mA/ µs		-	50	A/µs
I <sub>GM</sub>	peak gate current			-	1	А
V <sub>RGM</sub>	peak reverse gate voltage			-	5	V
P <sub>GM</sub>	peak gate power			-	2	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period		-	0.1	W
T <sub>stg</sub>	storage temperature			-40	150	°C
Tj	junction temperature			-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state.

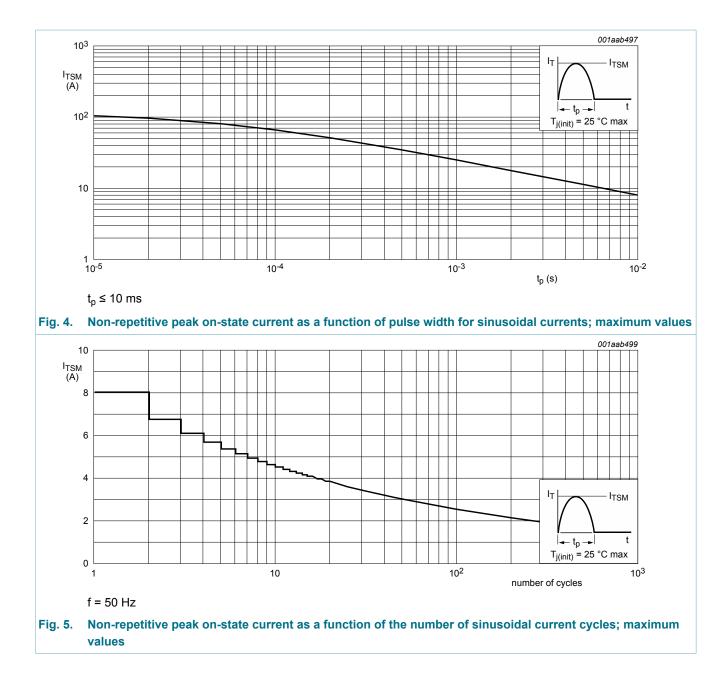
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## **BT168GW**

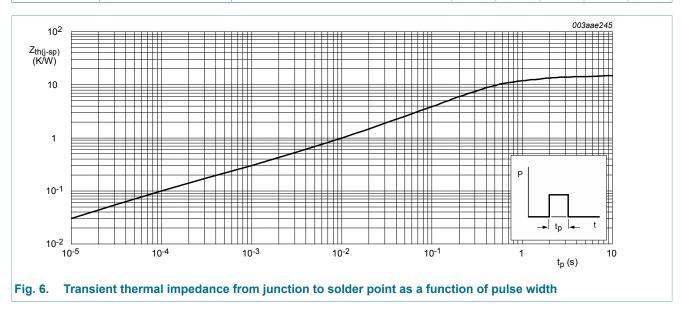
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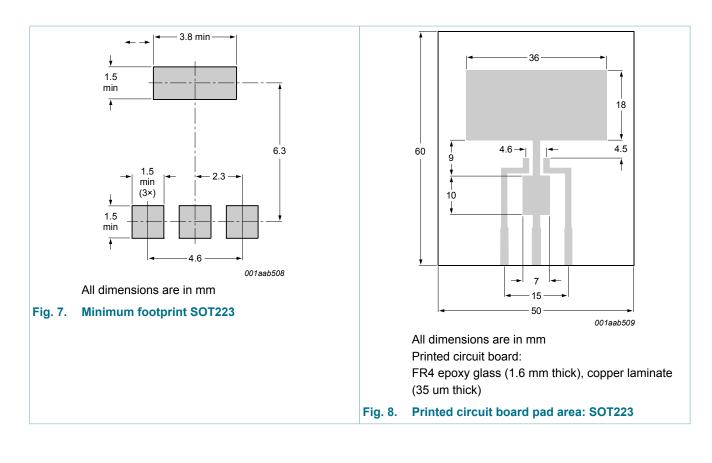
## 8. Thermal characteristics

Table 5. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	<u>Fig. 6</u>	-	-	15	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to	printed circuit board mounted; minimum footprint; Fig. 7	-	156	-	K/W
	ambient	printed circuit board mounted; pad area; Fig. 8	-	70	-	K/W



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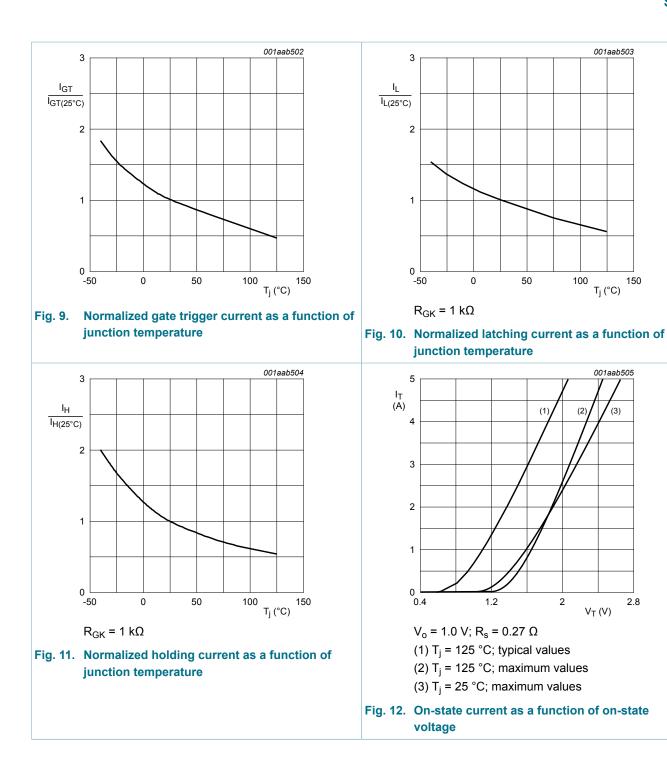
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## 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics			·		
I <sub>GT</sub>	gate trigger current	V <sub>D</sub> = 12 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 25 °C; Fig. 9	20	50	200	μA
IL	latching current	$V_D$ = 12 V; I <sub>G</sub> = 0.5 mA; R <sub>GK</sub> = 1 kΩ; T <sub>j</sub> = 25 °C; Fig. 10	-	2	6	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; R <sub>GK</sub> = 1 kΩ; T <sub>j</sub> = 25 °C; Fig. 11	-	2	5	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 1.2 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>	-	1.25	1.7	V
V <sub>GT</sub>	gate trigger voltage	V <sub>D</sub> = 12 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 25 °C; Fig. 13	-	0.5	0.8	V
		V <sub>D</sub> = 600 V; I <sub>T</sub> = 10 mA; T <sub>j</sub> = 125 °C	0.2	0.3	-	V
I <sub>D</sub>	off-state current	$V_{D}$ = 600 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 1 k $\Omega$	-	0.05	0.1	mA
I <sub>R</sub>	reverse current	$V_{R}$ = 600 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 1 k $\Omega$	-	0.05	0.1	mA
Dynamic c	haracteristics	I I				
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 402 V; T <sub>j</sub> = 125 °C; R <sub>GK</sub> = 1 kΩ; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; Fig. 14	500	800	-	V/µs
		$V_{DM}$ = 402 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit; Fig. 14	-	25	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$I_{TM}$ = 2 A; V <sub>D</sub> = 600 V; I <sub>G</sub> = 10 mA; dI <sub>G</sub> / dt = 0.1 A/µs; T <sub>j</sub> = 25 °C	-	2	-	μs
t <sub>q</sub>	commutated turn-off time	$\begin{split} V_{DM} &= 402 \text{ V};  \text{T}_{\text{j}} = 125 ^{\circ}\text{C};  \text{I}_{\text{TM}} = 1.6 \text{ A}; \\ V_{\text{R}} &= 35 \text{ V};  (\text{dI}_{\text{T}}/\text{dt})_{\text{M}} = 30  \text{A}/\text{\mu}\text{s};  \text{dV}_{\text{D}}/ \\ \text{dt} &= 2  \text{V}/\text{\mu}\text{s};  \text{R}_{\text{GK}} = 1  \text{k}\Omega;  (\text{V}_{\text{DM}} = 67\%  \text{of} \\ \text{V}_{\text{DRM}}) \end{split}$	-	100	-	μs

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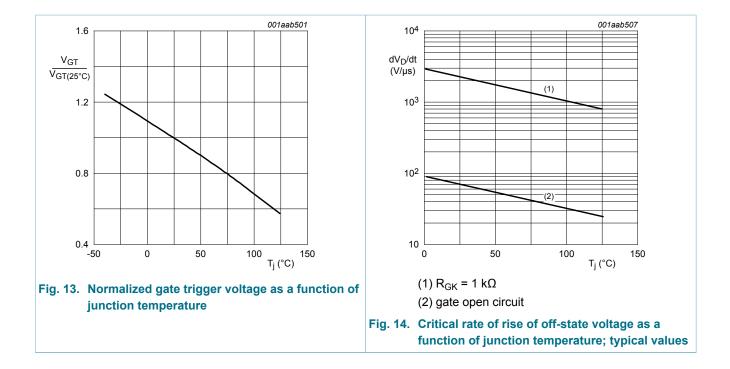
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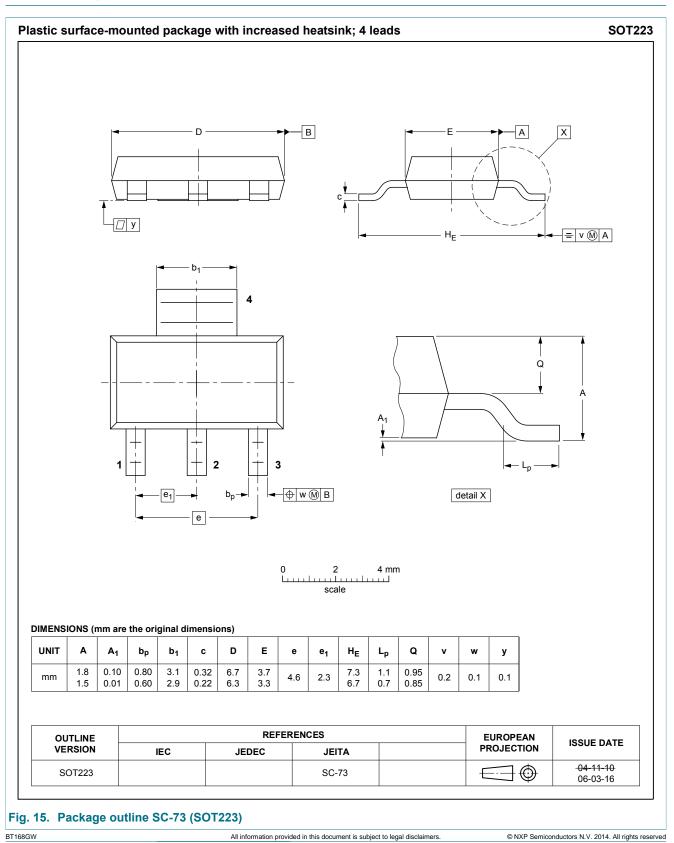
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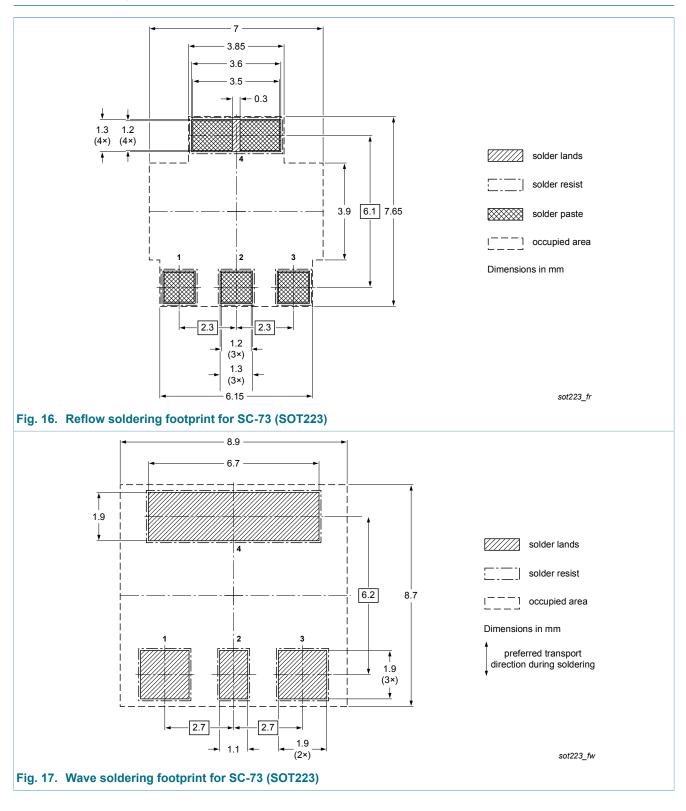
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## **10. Package outline**



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### 11. Soldering



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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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## 13. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Limiting values	3
8	Thermal characteristics	6
9	Characteristics	8
10	Package outline	11
11	Soldering	12
12	Legal information	13
12.1	Data sheet status	13
12.2	Definitions	13
12.3	Disclaimers	13
12.4	Trademarks	14

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